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PROVED BY: DATE	SHARP CORPORATION	REPRESENTATIVE DIVISION PHOTOVOLTAICS DIV.
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l. Ono- nov.12,1992	SPECIFICATION	□ ELECTRONIC COMPONENTS DIV.
	Y PAR	
DEVICE SPECIFICATIO)
		ness dealing name
PHOTOINTERRU	PTER	GP2S27T
		GP2S27T2
MODEL No.		GP2S27T3
		GP2S27T5
GP2S27T ser	IES	GP2S27T6
J. 202.	•	
)
important infor them without Sh 2. Please obey the (1) This device Main uses of Computer Measuring From applia (2) Please take in case this high reliability for the same automobile Fire box an (3) Please don't extremely him	e instructions mentioned below for is designed for general electron this device are as follows; OA equipment • Telecommunication equipment • Tooling machine • A ance, etc. proper steps in order to maintains device is used for the uses mentility. Training control and safety of a vehicle etc.) • Gas leak detection breath burglar alarm box • Other safet use for the uses mentioned below the safety of th	r cause anyone reproduce r actual use of this device. ic equipment. on equipment (Terminal) V equipment n reliability and safety, tioned below which require icle (air plane, train, ker ·Traffic signal ety equipment, etc. w which require
CUSTOMER'S APPROVAL		PRESENTED K. Elino
DATE		C. Ebina
		Department General Manager of Engineering Dept., II
		Opto-Electronic Devices Div.
		ELECOM Group
		SHARP CORPORATION

1. Application

This specification applies to the outline and characteristics of reflective type photointerrupter, Model No. GP2S27T series.

2. Outline

Refer to the attached drawing No. CY4607i02.

3. Ratings and characteristics

3.1 Absolute maximum ratings

Ta=25°C

	Parameter	Symbol	Rating	Unit
	Forward current	IF	50	mA
Input	Reverse voltage	, v _R	6	V
	Power dissipation	PD	75	mW
**************************************	Collector-emitter voltage	V _{CEO}	35	V
	Emitter-collector voltage	IF 50 V _R 6 P _D 75 Se V _{CEO} 35 Se V _{ECO} 6 Ic 20 Topr -25 ~ +	6	v
Output	Collector current	Ic	20	mA
	Collector power dissipation	Pc	75	mW
	Total power dissipation	Ptot	100	ww
	Operating temperature	Topr	-25 ∿ +85	°C
	Storage temperature	Tstg	-40 ∿ +100	°C

MODEL No. GP2S2/Tredies

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3.2 Electro-optical characteristics

Ta=25°C

Parameter			Symbol	MIN.	TYP.	MAX.	Unit	Conditions
	Forward voltage Reverse current		v _F	-	1.2	1.4	V	I _F =20mA
Input			IR	-	-	10	μА	v _R =6v
Output	Collector dark current		ICEO	-	1	100	nA	V _{CE} =20V
	*1 Collector current		Ic	20	45	120	μА	$V_{CE} = 2V$, $I_F = 4mA$
Transfer	*2 Leak current		ILEAK	-	-	100	nA	V _{CE} =2V, I _F =4mA
character- istics	· 1	(Rise)		-	20	100	μs	V _{CE} =2V, Ic=100μA
	*3 Response time (Fall)		tf	-	20	100	μs	RL=1000Ω, d=1mm

*1 The conditions and arrangement of the reflective object are shown below.

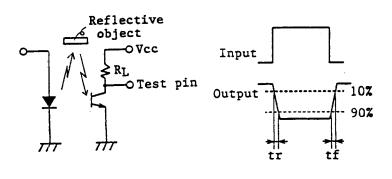
In regard to collector current (Ic), the following ranking shall be carried out.

Rank	Collector current Ic(µA)
A	20 ∿ 42
В	34 ∿ 71
С	58 ∿ 120

- *2 Without reflective object
- *3 d: Glass thickness of reflective mirror

(Test circuit for response time)

(Test arrangement for collector current)



Al evaporation
d=lmm-thick glass

4. Reliability

Refer to the attached sheet, Page 7, 8.

5. Incoming inspection

Refer to the attached sheet, Page 9.

6. Supplements

6.1 Device delivery shall be delivered model that has "O" marking in the rank table below. However, in case delivered model has 2 ranks or more, the quantity of each rank shall be not prescribed.

Collector current (Ic) rank table

Rank at delivery	Model No.	Ic (μA)	Rank
	GP2S27T	20 ∿ 120	A, B or C
	GP2S27T2	34 ∿ 71	В
	GP2S27T3	58 ∿ 120	С
	GP2S27T5	20 ~ 71	A or B
	GP2S27T6	34 ∿ 120	B or C

Test conditions		
V _{CE} =2V		
I _F =4mA		
Ta=25°C		

6.2 Parts

Refer to the attached sheet, Page 10.



7. Notes

- 1) In circuit designing, make allowance for the degradation of the light emitting diode output that results from long continuous operation. (MAX.: 50% degradation/5 years)
- 2) To prevent photointerrupter from faulty operation caused by external light, do not set the detecting surface face to the external light.
- 3) The distance between the photointerrupter and the object to be detected shall be determined the distance by referencing attached graph "Relative collector current vs. distance".
- 4) Soldering
 - (1) Solder reflow

Please do only one soldering at the temperature and the time within the temperature profile in page 12.

(2) Soldering by hand

To solder onto lead pins, please solder at 260°C for 3 seconds or less. And please take care not to let any external force exert on lead pins when soldering.

- 5) Cleaning shall carry out as the below items to avoid keeping solvent, solder and flux on the device.
 - (1) Solvent cleaning: Solvent temperature 45°C or less Immersion 3 min. or less
 - (2) Ultrasonic cleaning: Please don't carry out ultrasonic cleaning.
 - (3) The cleaning shall be carried out with solvent below.

Solvent: Ethyl alcohol, Methyl alcohol, Freon TE·TF Daiflon-solvent S3-E

(4) Please refrain from using Chloro Fluoro Carbon type solvent to clean devices as much as possible since it is internationally restricted to protect the ozonosphere. Before you use alternative solvent you are requested to confirm that it does not damage package resin.

8. Others

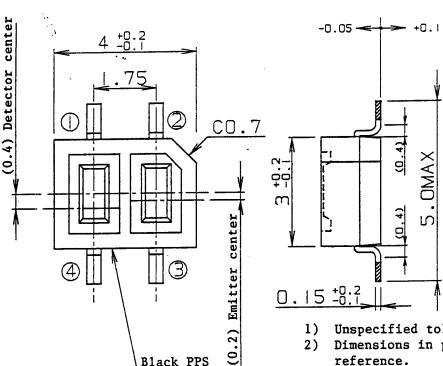
Any doubt as to this specification shall be determined in good faith upon mutual consultation of the both parties.

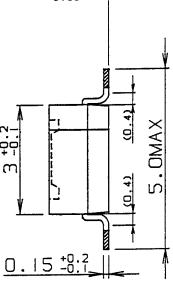
REFERENCE

2. Outline Dimensions (Drawing No. CY4607i02)

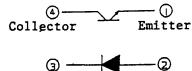
Scale : 10/1

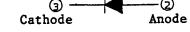
Unit: 1/1mm



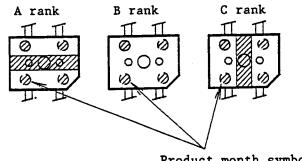


- Unspecified tolerance shall be ±0.15.
- Dimensions in parenthesis are shown for reference.
- 3) Parrallel balance of 4 lead pins shall be within ±0.15.
- 4) The dimensions shown do not include those of burrs. Burr's dimensions shall be 0.15 MAX..
- 5) Internal connection diagram is shown below.



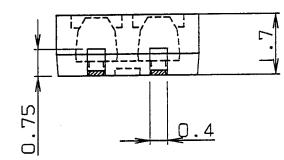


6) Marked face shall be surface A. The symbols of rank mark and production month is as follows.

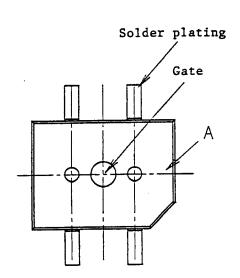


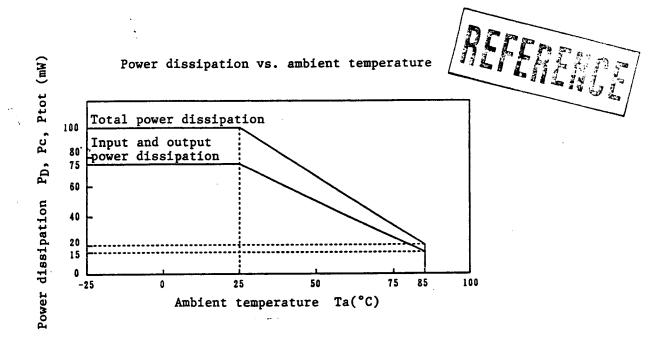
Product month symbol

The oblique portions are no solder plating area.

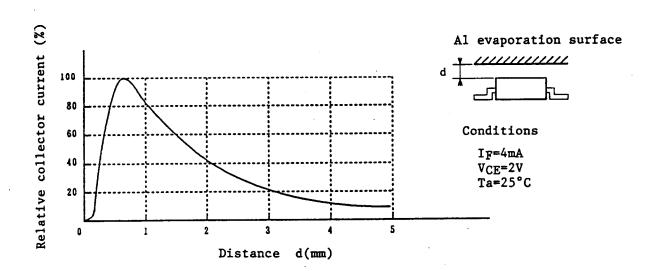


Black PPS





Relative collector current vs. distance (reference)





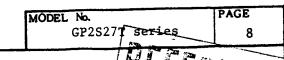
4. Reliability

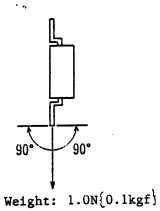
The reliability of products shall be satisfied with items listed below.

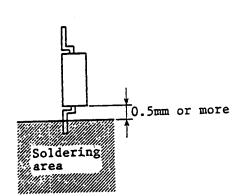
Confidence level: 90% LTPD: 10%/20%

Test Items	Test Conditions	Failue Judgement Criteria	Samples (n) Defective(c)
Temperature cycling	1 cycle -40°C ~ +100°C (30min.) (30min.) 20 cycle test	. V _F ≥ U × 1.2	n=22, c=0
Humidity storage	+60°C, 90%RH, 500h	$Ic \leq L \times 0.8$	n=22, c=0
High temp. storage	+100°C, 500h	I _{LEAK} ≥ U × 2	n=22, c=0
Low temp. storage	-40°C, 500h	IR ≥ U × 2	n=22, c=0
Operation life	I _F =50mA, Ta=25°C, 500h Ptot=100mW	I _{CEO} ≥ U × 2	n=22, c=0
Mechanical shock	15000m/s ² {1500G}, 0.5ms, 3 times/±X, ±Y, ±Z direction		n=11, c=0
Variable frequency vibration	100 \(2000 \(\) 100 \(\) Hz/20min. 2h/X,Y,Z direction 100m/s ² {10G}		n=11, c=0
Terminal strength (Tension)	Weight: 3N{0.3kgf} 30 s/each terminal	U: Upper specificaiton limit	n=11, c=0
Terminal strength (Bending)	Weight: lN{0.1kgf} 0°+90°+0° 2 times bending	L: Lower specification	n=11, c=0
Soldering heat	260°C, 3s Immerse up to 0.5mm from the bottom face of package.	limit	n=11, c=0
Solderability	230°C, 3 s Prior disposition: Dip rogin flux. Then immerse up to 0.5mm from the bottom face of package.	Judgement only appearance Solder shall adhere at the aera of 95% or more of dipped portion	n=11, c=0

For details, conforms to JIS C 7021.







4.1 Solder reflow

Confidence level: 90% LTPD: 10%/ 20%

Test Item	Test condition	Failure Judgement Criteria	Samples (n) Defective(c)
Solder reflow	Refer to the attached sheet, Page 12. 1 time	Ic < L × 0.8	n=22, c=0

1	MODEL No.	PAGE
	GP2S27T series	9
		<u>!</u>

REFERENCE

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- 5. Incoming inspection
 - 5.1 Inspection items
 - (1) Electrical characteristics $v_F, \ I_R, \ Bv_{ECO}, \ Bv_{CEO}, \ I_CEO$
 - (2) Appearance
 - 5.2 Sampling method and Inspection level

A single sampling plan, normal inspection level II based on MIL-STD-105D is applied. The AQL according to the inspection items are shown below.

Defect	Inspection item	AQL(%)
Major defect	Characteristics defect	0.1
derect	Unreadable marking	
Minor defect	Appearance defect except the above mensioned. *	0.4

- * Crack Visible crack shall be defect.
- Split
 * Chip One which affects the electrical
 Scratch characteristics shall be defect.
 The others
- * Void One which is void across central separator on photo sensor shall be defect.



The other place voids, one which affects the electrical characteristics shall be defect.

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	GP2S27T series	10

6. Supplements

6.1 Parts

This product uses the below parts.



6.1.1 Light detector

Type	Material	Maximum sensitivity wavelength (nm)	Sensitivity wavelength (nm)	Response time (µs)
Phototran- sistor	Silicon (Si)	800	700 ∿ 1200	20

6.1.2 Light emitter

Туре	Material	Maximum light emitting wavelength (nm)	I/O Frequency (MHz)
Infrared light emitting diode (non-coherent)	GaAs	950	0.3

6.1.3 Material

Case	Lead frame	Lead frame plating
Black PPS resin	42 Alloy	Solder plating

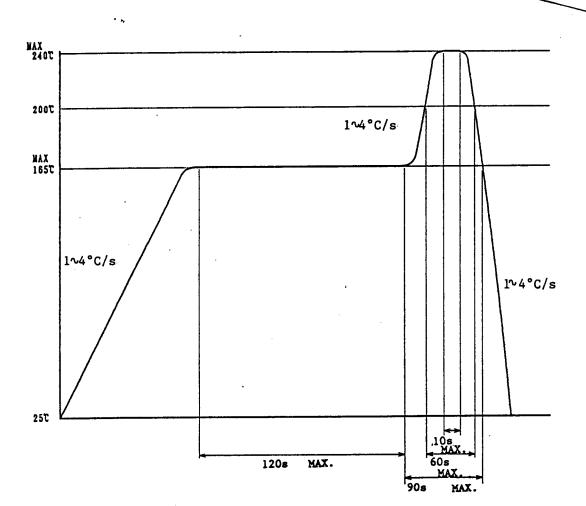
6.1.4 Others

This product shall not be proof against radiation flux.

Precautions for Soldering photointerrupter

1. In case, solder reflow

Please do only one soldering at the temperature and the the temperature profile as shown in the figure.



2. Other precautions

An infrared lamp used to heat up for soldering may cause a localized temperature rise in the resin. So keep the package temperature within that specified in Item 1. Also avoid immersing the resin part in the solder. Even if within the temperature profile above, there is the possibility that the gold wire in package is broken in case that the deformation of PWB gives the affection to lead pins. Please use after confirmation the conditions fully by actual solder reflow machine.

Package specifications (\$178mm reel)

1. Application

This specification applies to the taping specifications and the relation items for the GP2S27T series.

- 2. Taping method
- (2.1) Tape structure and Dimensions (Refer to the attached sheet-2-2)

The tape shall have a structure in which a cover tape is sealed heatpressed on the carrier tape of hard vinyl-chloride to protect against static electricity.

(2.2) Reel structure and Dimensions (Refer to the attached sheet-2-3)

The taping reel shall be corrugated cardboard-made with its dimensions as shown in the attached drawing.

(2.3) Direction of product insertion (Refer to the attached sheet-2-3)

Product direction in carrier tape shall direct to the anode mark at the hole side on the tape.

3. Adhesiveness of cover tape

The exfoliation force between carrier tape and cover tape shall be 0.2N{0.02kgf} to 1N{0.1kgf} for the angle from 160° to 180°.

4. Rolling method and quanfity

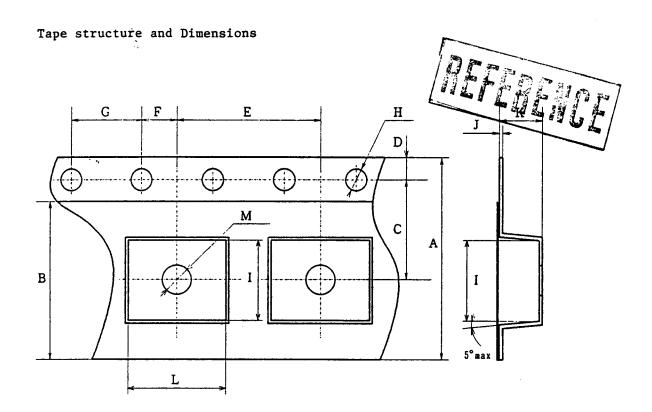
Wind the tape back on the reel so that the cover tape will be outside the tape. Attach more than 20cm of blank tape to the trailer and the leader of the tape and fix the both ends with adhesive tape. One reel shall contain 1000 pcs.

5. Marking

The outer packaging case shall be marked with following information.

- * Model No. * Number of pieces delivered * Production date
- 6. Safety protection during shipping

There shall be no deformation of component or degradation of electrical characteristecs due to shipping.

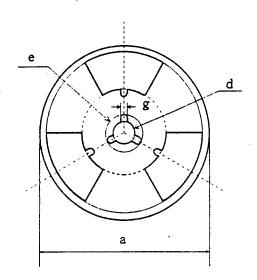


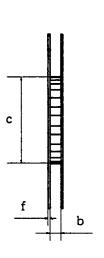
Symbo Unit	A	В	С	D	E	F
m m	±0.3 12.0	7. $6^{\pm 0.3}$	±0.05 5.5	±0.1 1.75	±0.1 8.0	±0. 05 2. 0

Symbol Unit	G	Н	I	J	K	L	М
m m	±0.1 4.0	\$\frac{\pm 0.1}{0.0} \\ \phi 1.5	±0.1 4.4	±0.05 0.3	2. 0 ± 0. 1	±0. 1 5. 2	$ \frac{\pm 0.1}{60} $

Reel structure and Dimensions

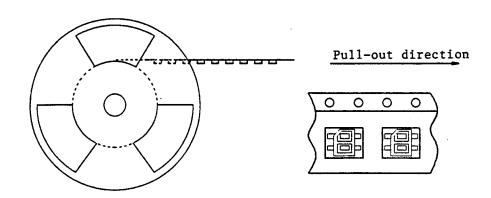






Symbol	Check word						
Unit	а	b	С	d	е	f	g
m m	178	13. 5±1	80±0. 1	13±0.5	23±1	2. 0±0. 5	2. 5±0. 5

Direction of product insertion



Moisture-proof package specification (\$178mm reel)

1. Application

This specification applies to the products which Sharp delivers to customer.

2. Packaging specifications

2.1 Packaging material

Name	Marerial	Q'ty	Aim
Aluminium laminated sack	Aluminium polyethylene	Refer to 2.2	Moisture-proof
Label	Paper(-made)	-	Indication of Model No. and Q'ty

2.2 Packaging method

- (1) Seal the aluminium laminated sack included the ruled tape-reel quanfity.
- (2) Fill up the blank of label and paste on the sack.
- (3) Put the moisture-proof laminated sack in the ruled case.

Packaging shape	Product	Q'ty	Moisture-proof sack Q'ty	
Tape-reel(\$178mm)	1ch. type	1000 pcs./reel	lreel/sack	

Minimum order Q'ty : 1 reel/sack

3. Strage and management after open

3.1 Storage condition: Storage shall be in accordance with the below conditions.

Storage temp. : 5 to 30°C

Storage humidity: 70%RH or less

- 3.2 Treatment after open
- (1) After open, please mount at the conditions of humidity 60%RH or less and temperature 5 to 25°C within 2 days.
- (2) In case of long time storage after open, please mount at the conditions of humidity 70%RH or less and temperature 5 to 30°C within 2 weeks by using dry box or resealing with desiccant in moisture-proof sack by sealer.
- 3.3 Baking before mounting

In case that it could not carry out the above treatment, it is able to mount by baking treatment. However baking treatment shall be limited only 1 time.

Recomended conditions: 125°C, 16 to 24 hours

* Baking treatment can not carry out at the packaged condition. please carry out baking at the condition of mounting on PWB or getting on the metal tray.

SPECIFICATIONS ARE SUBJECT TO CHANGE WITHOUT NOTICE.

Suggested applications (if any) are for standard use; See Important Restrictions for limitations on special applications. See Limited Warranty for SHARP's product warranty. The Limited Warranty is in lieu, and exclusive of, all other warranties, express or implied. ALL EXPRESS AND IMPLIED WARRANTIES, INCLUDING THE WARRANTIES OF MERCHANTABILITY, FITNESS FOR USE AND FITNESS FOR A PARTICULAR PURPOSE, ARE SPECIFICALLY EXCLUDED. In no event will SHARP be liable, or in any way responsible, for any incidental or consequential economic or property damage.



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